IN THE CLAIMS

Please amend the claims as follows. This listing of claims will replace all prior versions, and listings, of claims in the application.

- 1. (currently amended) An product suitable for simulating a standard wafer in semiconductor manufacturing equipment, comprising:
 - a first layer composed of a material suitable for being handled by the semiconductor manufacturing equipment; and
 - a second layer composed of a mixture of multiple materials disposed entirely over the first layer, the mixture of the multiple materials configured to simultaneously generate byproducts during an etching operation, wherein the byproducts are <u>selected</u> from the group consisting of aluminum, silicon, tungsten, tungsten silicide, titanium, titanium nitride, silicon dioxide, platinum, ruthenium, ruthenium oxide, copper, tantalum, and nickel similar to byproducts produced by the standard wafer.
- 2. (previously amended) The product of claim 1, wherein the multiple materials include a photoresist and a metal.
- 3. (previously amended) The product of claim 1, wherein the multiple materials include both a polymer and a material selected from the group consisting of silicon, tungsten, tungsten silicide, titanium, titanium nitride, silicon dioxide, aluminum, platinum, ruthenium, ruthenium oxide, copper, tantalum, and nickel.

Claims 4-15 (canceled)

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16. (previously amended) The product of claim 1, wherein the mixture of multiple

materials includes three or more materials.

17. (previously amended) The product of claim 1, wherein the second layer is

capable of withstanding cumulative etching time of up to 120 radio frequency minutes.

18. (previously amended) The product of claim 1, wherein the mixture of the

multiple materials are baked on the first layer.

19. (previously amended) The apparatus of claim 1, wherein a ratio of the multiple

materials in the mixture corresponds to an exposed area on the standard wafer being

simulated.